Vishay Semiconductors

High Performance Schottky Rectifier, 2.1 A

Anode

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www.vishay.com

SMA

PRODUCT SUMMARY					
Package	SMA				
I _{F(AV)}	2.1 A				
V _R	100 V				
V _F at I _F	0.78 V				
I _{RM}	1 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	1.0 mJ				

FEATURES

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10MQ100NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS				
I _{F(AV)}	DC	2.1	A			
V _{RRM}		100	V			
I _{FSM}	t _p = 5 μs sine	120	А			
V _F	1.5 A _{pk} , T _J = 125 °C	0.68	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-10MQ100NPbF	UNITS			
Maximum DC reverse voltage	V _R	100	V			
Maximum working peak reverse voltage	V _{RWM}	100	v			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T_L = 126 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		1.5	А	
Maximum peak one cycle non-repetitive surge current, T ₁ = 25 °C		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А	
non-repetitive surge current, $I_J = 25$ °C I_{FSM} See fig. 6		10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	30		
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 0.5 \text{ A}, L = 8 \text{ mH}$		1.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А	

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VS-10MQ100NPbF



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS	
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.78	v
		1.5 A		0.85	
		1 A	T 405.00	0.63	
		1.5 A	T _J = 125 °C	0.68	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Detect V	0.1	mA
See fig. 2		T _J = 125 °C	V _R = Rated V _R	1	
Threshold voltage	V _{F(TO)}		0.52	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		78.4	mΩ
Typical junction capacitance	CT	V_R = 10 V_{DC} , T_J = 25 °C, test signal = 1 MHz		38	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 2.0		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/		V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W	
Approvimeto weight			0.07	g	
Approximate weight			0.002	oz.	
Marking device		Case style SMA (similar D-64)	V1	J	

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

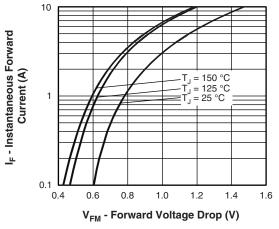


Fig. 1 - Maximum Forward Voltage Drop Characteristics

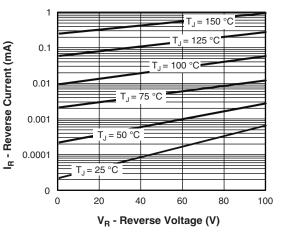
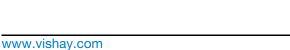


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

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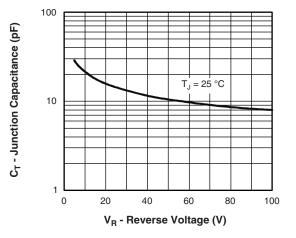


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

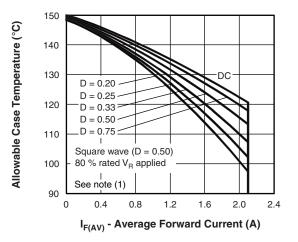
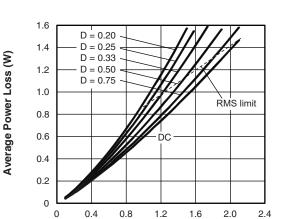


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

Note



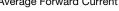
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VS-10MQ100NPbF

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2.0





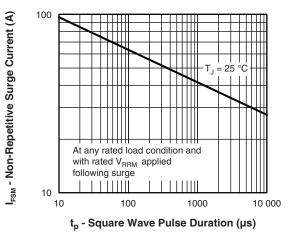


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

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ORDERING INFORMATION TABLE

Device code	VS-	10	м	Q	100	N	TR	PbF
		2	3	4	5	6	7	8
	<u> </u>	Visl	nay Sem	niconduc	ctors pro	oduct		
	2 -	Cur	rent rati	ng				
	3 -	- M =	SMA					
	4 -	Q =	Schottk	ky "Q" se	eries			
	5 -	Vol	tage rati	ng (100	= 100 \	/)		
	6 -	N =	new SN	ΛA				
	7 -	• N	one = bo	ox (1000) pieces)		
		• TI	R = tape	and ree	el (7500	pieces)	
	8 -	PbF	= lead	(Pb)-fre	е		-	

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95018</u>					
Part marking information		www.vishay.com/doc?95029			
Packaging information	Tape and reel	www.vishay.com/doc?95034			
Packaging information	Bulk	www.vishay.com/doc?95397			
SPICE model		www.vishay.com/doc?95371			

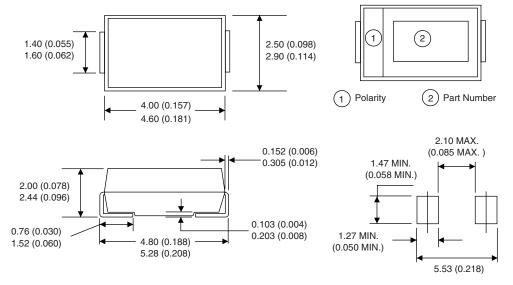


Outline Dimensions

Vishay High Power Products

SMA

DIMENSIONS in millimeters (inches)



Soldering pad



Vishay

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